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L-53F3C

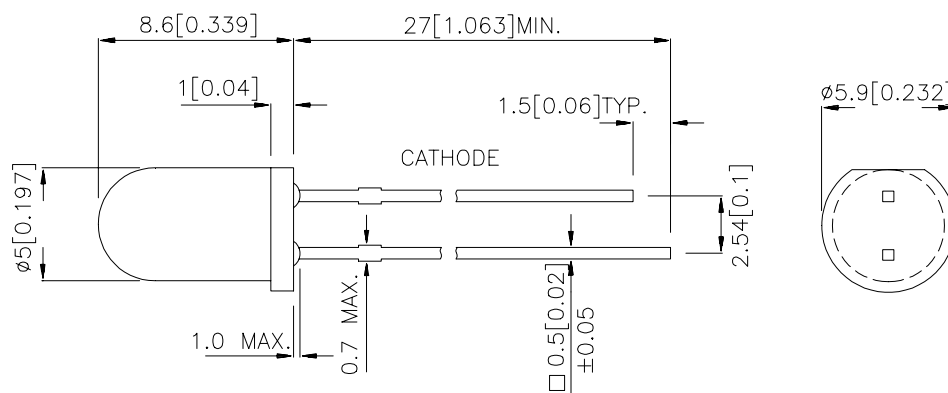
Features

- MECHANICALLY AND SPECTRALLY MATCHED TO THE L-51P3C PHOTOTRANSISTOR.
- WATER CLEAR LENS AVAILABLE HIGH POWER OUTPUT.

Description

F3 Made with Gallium Arsenide Infrared Emitting diodes.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) @20mA *50mA		Viewing Angle
			Min.	Typ.	2θ1/2
L-53F3C	GaAs	WATER CLEAR	7	20	30°
			*10	*30	30°

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

2. * Luminous intensity with asterisk is measured at 50mA.

Electrical / Optical Characteristics at T_A=25°C

Item	P/N	Symbol	Typ.	Max.	Unit	Condition
Forward Voltage	F3	V _F	1.2	1.6	V	I _F =20mA
Reverse Current	F3	I _R	-	10	uA	V _R =5V
Capacitance	F3	C	90	-	pF	V _F =0V; f=1MHz
Peak Wavelength	F3	λ _P	940	-	nm	I _F =20mA
Spectral Line Half-width	F3	Δλ 1/2	50	-	nm	I _F =20mA

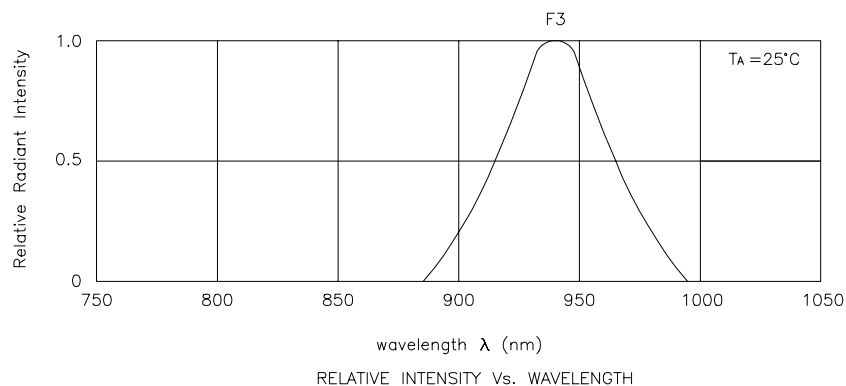
Absolute Maximum Ratings at T_A=25°C

Item	Symbol	F3	Units
Power Dissipation	P _T	100	mW
DC Forward Current	I _F	50	mA
Peak Forward Current [1]	i _{FS}	1.2	A
Reverse Voltage	V _R	5	V
Operating /Storage Temperature	-40° C To +85°C		
Lead Solder Temperature [2]	260°C For 5 Seconds		

Notes:

1. 1/100 Duty Cycle, 10us Pluse Width.

2. 2mm below package base.



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